DS 28: Invited Talk - Heidemarie Schmidt (Joint Session with DF, MA, HL, KR, MM)

Time: Wednesday 15:00–15:45 Location: GER 37

Invited Talk DS 28.1 Wed 15:00 GER 37 Smart multiferroic thin films for cognitive computing — •Heidemarie Schmidt — Technische Universität Chemnitz, Department of Materials for Nanoelectronics, Reichenhainer Str. 39, 09126 Chemnitz

Cognitive systems promise to penetrate complexity and assist people and organizations in better decision making [1]. We have successfully prepared metal-multiferroic-metal (MMM) structures with the multiferroic material BiFeO3 and BiFeTiO3. All those MMM structures exhibit nonvolatile resistive (meristive) switching. Investigations of memristive switching is driven by promising applications of power-efficient memristive nanostructures including data storage, logic systems, cog-

nitive computing and artificial neural networks. Prominence of work on memristive systems might be visualized by the near-future breakthrough in computing technology, where classical Von Neumann architecture is replaced by cognitive systems. In this talk I present three new functionalities of smart MMM structures including nonvolatile multilevel resistive switching [2], nonvolatile reconfigurable logics and nonvolatile second and higher harmonics generation [3] which are very promising for the development of cognitive computing. [1] J. E. Kelly III, S. Hamm, Smart Machines: IBM*s Watson and the Era of Cognitive Computing, Columbia University Press, 2013 [2] Y. Shuai et al., J. Appl. Phys. 109 (2011); Appl. Phys. Lett. 98 (2011); Appl. Phys. Exp. 4 (2011); 111 (2012); IEEE Electron Device Letters 34 (2013); Scientific Reports 3 (2013) [3] N. Du et al., Rev. Sci. Instr. 84 (2013)